onsemi

TinyLogic UHS Dual Buffer with 3-STATE Outputs

NC7WZ125

Description

The NC7WZ125 is a Dual Non–Inverting Buffer with independent active LOW enables for the 3–STATE outputs. The Ultra High Speed device is fabricated with advanced CMOS technology to achieve superior switching performance with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} operating range. The inputs and outputs are high impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V independent of V_{CC} operating range. Outputs tolerate voltages above V_{CC} when in the 3–STATE condition.

Features

- Space Saving US8 Surface Mount Package
- MicroPakTM Pb–Free Leadless Package
- Ultra High Speed: tPD 2.6 ns Typ. into 50 pF at 5 V VCC
- High Output Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Matches the Performance of LCX when Operated at 3.3 V V_{CC}
- Power Down High Impedance Inputs / Outputs
- Overvoltage Tolerant Inputs Facilitate 5 V to 3 V Translation
- Outputs are Overvoltage Tolerant in 3-STATE Mode
- Proprietary Noise / EMI Reduction Circuitry Implemented
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

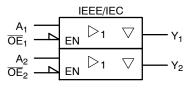
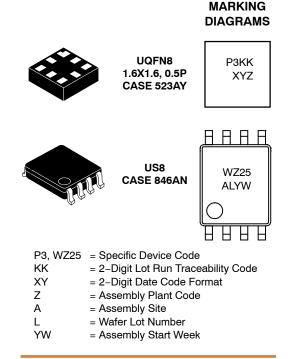


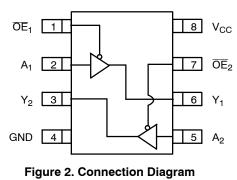
Figure 1. Logic Symbol



ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

Connection Diagrams



(Top View)

PIN DESCRIPTIONS

Pin Names	Description
O E _n	Enable Inputs for 3-STATE Outputs
A _n	Input
Y _n	3-STATE Outputs

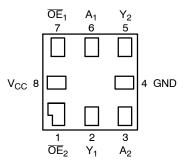


Figure 3. Pad Assignments for MicroPak (Top Thru View)

FUNCTION TABLE

Inp	Output		
ŌĒ	OE A _n		
L	L	L	
L	н	Н	
Н	L	Z	
Н	Н	Z	

H = HIGH Logic Level L = LOW Logic Level Z = 3-STATE

ABSOLUTE MAXIMUM RATINGS

Symbol	Paramet	Min	Мах	Unit	
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage (Note 1)		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
Ι _{ΙΚ}	DC Input Diode Current V _{IN} < 0 V		-	-50	mA
Ι _{ΟΚ}	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
I _{OUT}	DC Output Source / Sink Current		-	±50	mA
I _{CC} / I _{GND}	DC V _{CC} / Ground Current		-	±100	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Junction Lead Temperature under B	-	+150	°C	
ΤL	Junction Lead Temperature (Solder	-	+260	°C	
PD	Power Dissipation in Still Air	US8 MicroPak-8	- -	500 539	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

Symbol		Parameter	Min	Max	Unit		
V _{CC}	Supply Voltage Operating		Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Rete	ntion	1.5	5.5			
V _{IN}	Input Voltage		0	5.5	V		
V _{OUT}	Output Voltage	Active State	0	V _{CC}	V		
		3-STATE	0	5.5	V		
T _A	Operating Temperature		-40	+85	°C		
t _r , t _f	Input Rise and Fall Time	V_{CC} @ 1.8 V ±0.15 V, 2.5 V ±0.2 V	0	20	ns/V		
		V _{CC} @ 3.3 V ±0.3 V	0	10			
		V _{CC} @ 5.0 V ±0.5 V	0	5			
θ_{JA}	Thermal Resistance US8 MicroPak-8		- -	250 232	°C/W		

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTICAL CHARACTERISTICS

					Т	T _A = +25°C			T _A = −40 to +85°C	
Symbol	Parameter	Conc	litions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
V _{IH} HIGH Level Input Voltage				1.65 to 1.95	0.65 V _{CC}	-	-	0.65 V _{CC}	_	V
				2.3 to 5.5	0.7 V _{CC}	-	-	0.7 V _{CC}	_	
V _{IL}	LOW Level Input			1.65 to 1.95	-	-	0.35 V _{CC}	-	0.35 V _{CC}	V
	Voltage			2.3 to 5.5	-	-	0.3 V _{CC}	-	0.3 V _{CC}	
V _{OH}	HIGH Level Output	$V_{IN} = V_{IH}$ or	I _{OH} = -100 μA	1.65	1.55	1.65	-	1.55	_	V
	Voltage	VIL		2.3	2.2	2.3	-	2.2	-	
				3.0	2.9	3.0	-	2.9	-	
				4.5	4.4	4.5	-	4.4	-	
		V _{IN} = V _{IH} or	I _{OH} = -4 mA	1.65	1.29	1.52	-	1.29	-	
	VIL	I _{OH} = -8 mA	2.3	1.9	2.15	-	1.9	-		
		I _{OH} = -16 mA	3.0	2.4	2.80	-	2.4	-		
		I _{OH} = -24 mA	3.0	2.3	2.68	-	2.3	-		
		I _{OH} = -32 mA	4.5	3.8	4.20	-	3.8	-		
V _{OL}	LOW Level Output	$\begin{array}{llllllllllllllllllllllllllllllllllll$	l _{OL} = 100 μA	1.65	-	0.0	0.10	-	0.10	V
	voitage			2.3	-	0.0	0.10	-	0.10	
				3.0	-	0.0	0.10	-	0.10	
				4.5	-	0.0	0.10	-	0.10	
			I _{OL} = 4 mA	1.65	-	0.08	0.24	-	0.24	
			I _{OL} = 8 mA	2.3	_	0.10	0.3	_	0.3	
			I _{OL} = 16 mA	3.0	_	0.15	0.4	_	0.4	
			I _{OL} = 24 mA	3.0	-	0.22	0.55	-	0.55	
			I _{OL} = 32 mA	4.5	-	0.22	0.55	-	0.55	
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V, G	ND	1.65 to 5.5	-	-	±0.1	_	±1	μA
I _{OZ}	3-STATE Output Leakage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $0 \le V_{OUT} \le 5.5 \text{ V}$		1.65 to 5.5	-	-	±0.5	_	±5	μA
I _{OFF}	Power Off Leakage Current	V_{IN} or V_{OUT} = 5.5 V		0.0	-	-	1	_	10	μA
I _{CC}	Quiescent Supply Current	V _{IN} = 5.5 V, GI	ND	1.65 to 5.5	-	-	1	-	10	μΑ

NOISE CHARACTERISTICS

				T _A = +25°C		
Symbol	Parameter	Conditions	V _{CC} (V)	Тур Мах		Unit
V _{OLP} (Note 3)	Quiet Output Maximum Dynamic V _{OL}	C _L = 50 pF	5.0	-	1.0	V
V _{OLV} (Note 3)	Quiet Output Minimum Dynamic V _{OL}	C _L = 50 pF	5.0	-	1.0	V
V _{OHV} (Note 3)	Quiet Output Minimum Dynamic V _{OH}	C _L = 50 pF	5.0	-	4.0	V
V _{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	C _L = 50 pF	5.0	-	3.5	V
V _{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	C _L = 50 pF	5.0	-	1.5	V

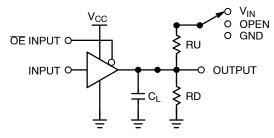
3. Parameter guaranteed by design.

AC ELECTRICAL CHARACTERISTICS

	Parameter			T _A = +25°C			T _A = -40	to +85°C			
Symbol		Conditions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit		
t _{PLH} , t _{PHL}	Propagation Delay	$\begin{array}{l} C_L = 15 \text{ pF} \\ R_D = 1 \text{ M}\Omega \\ \text{S1 = Open} \end{array}$	1.8 ±0.15	_	-	12.0	-	13.0	ns		
	A _N to Y _N (Figure 4, 6)		2.5 ±0.2	-	-	7.5	-	8.0			
			3.3 ±0.3	-	-	5.2	-	5.5			
			5.0 ±0.5	_	-	4.5	-	4.8			
		$C_{L} = 50 \text{ pF},$	3.3 ±0.3	_	-	5.7	-	6.0			
		R _D = 500 Ω S1 = Open	5.0 ±0.5	_	-	5.0	-	5.3			
t _{OSLH} , t _{OSHL}		C _L = 50 pF,	3.3 ±0.3	_	-	1.0	-	1.0	ns		
(Note 4) (Figure 4, 6)	R _D = 500 Ω S1 = Open			R _D = 500 Ω S1 = Open	5.0 ±0.5	-	-	0.8	-	0.8	
t _{PZL} , t _{PZH}	Output Enable Time	$\begin{array}{llllllllllllllllllllllllllllllllllll$	1.8 ±0.15	-	-	14.0	-	15.0	ns		
	(Figure 4, 6)		2.5 ±0.2	-	-	8.5	-	9.0			
			3.3 ±0.3	-	-	6.2	-	6.5			
			5.5 ±0.5	_	-	5.5	-	5.8			
t _{PLZ} , t _{PHZ}	Output Disable Time	C _L = 50 pF	1.8 ±0.15	_	-	12.0	-	13.0	ns		
	(Figure 4, 6)	$R_D, R_U = 500 \Omega$ S1 = GND for t _{PZH}	2.5 ±0.2	_	-	8.0	-	8.5			
		$S1 = V_I \text{ for } t_{PZL}$ $V_I = 2 \times V_{CC}$	3.3 ±0.3	_	-	5.7	-	6.0			
		5.0 ±0.5	_	-	4.7	-	5.0				
C _{IN}	Input Capacitance		0	-	2.5	-	-	-	pF		
C _{OUT}	Output Capacitance		5.0	-	4	-	-	-	pF		
C _{PD}	Power Dissipation	(Note 5)	3.3	-	10	-	-	-	pF		
	Capacitance (Figure 5)	pacitance (Figure 5)	5.0	_	12	-	-	-	1		

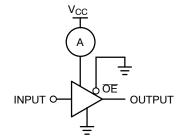
4. Parameter guaranteed by design. t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|; t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|.
5. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (see Figure 5) C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).

AC Loading and Waveforms



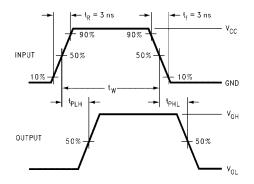
 C_L includes load and stray capacitance Input PRR = 1.0 MHz; t_W = 500 ns

Figure 4. AC Test Circuit



Input = AC Waveform; $t_r = t_f = 1.8$ ns; PRR = 10 MHz; Duty Cycle = 50%.

Figure 5. I_{CCD} Test Circuit



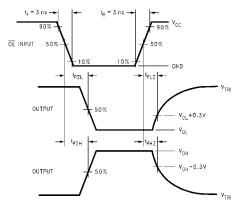


Figure 6. AC Waveforms

ORDERING INFORMATION

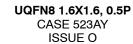
Order Number	Top Mark	Package	Shipping [†]
NC7WZ125K8X	WZ25	8-Lead US8, JEDEC MO-187, Variation CA 3.1 mm Wide	3000 / Tape & Reel
NC7WZ125L8X	P3	8–Lead MicroPak, 1.6 mm Wide (Pb–Free)	5000 / Tape & Reel
NC7WZ125L8X-L22185	P3	8-Lead MicroPak, 1.6 mm Wide (Pb-Free)	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

6. Pb-Free package per JEDEC J-STD-020B.

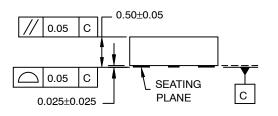
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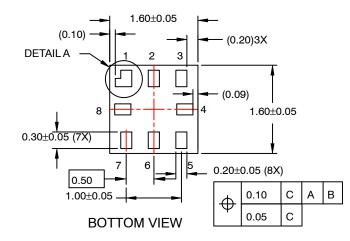


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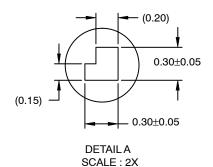
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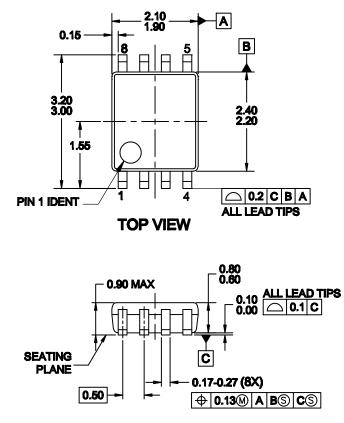
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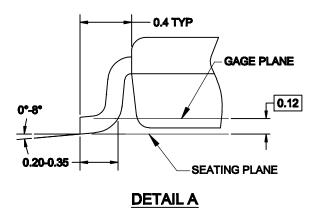


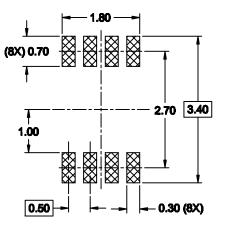
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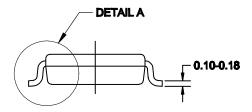




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